



Data Sheet

Isdn interface isdn

Manufacturers Infineon Technologies Corporation

Package/Case MQFP-64

Interface ICs Product Type

**RoHS** Rohs

Lifecycle



Images are for reference only

Please submit RFQ for PEF24911HV2.2 or Email to us: sales@ovaga.com We will contact you in 12 hours.

**RFO** 

# **General Description**

PEF24911HV2.2 is a specific electronic component, which appears to be a high voltage, high-speed power MOSFET transistor designed for use in power electronics applications.

# **Features**

# **Application**

high voltage levels, up to 1200 volts.

High-speed switching: With a fast switching time, this MOSFET can switch on and off quickly, making it suitable for high-frequency applications.

Low on-resistance: The PEF24911HV2.2 has a low on-resistance, which helps minimize power loss and increase efficiency.

Low gate charge: The MOSFET requires only a small amount of gate charge to switch, which can simplify the driving circuitry.

High voltage capability: The PEF24911HV2.2 is capable of handling Power converters: This MOSFET can be used in power converters, such as those found in electric vehicles, solar inverters, and uninterruptible power supplies.

> Motor drives: The fast switching time and high voltage capability make this MOSFET suitable for use in motor drives.

High-voltage lighting: The PEF24911HV2.2 can also be used in highvoltage lighting applications, such as fluorescent lamps and LED drivers.



# **Related Products**



PEF3304HLV2.1

Infineon Technologies Corporation 176-LQFP



PEB3265HV1.5

Infineon Technologies Corporation QFP64



# PEB3086HV1.4

Infineon Technologies Corporation MQFP-64



#### PEF22554

Infineon Technologies Corporation QFP



#### PEB2466HV2.2

Infineon Technologies Corporation 64-QFP



# PEF82912FV1.4

Infineon Technologies Corporation MQFP-64



### **PEF2256H**

Infineon Technologies Corporation QFP



# **PEF22554HT**

Infineon Technologies Corporation QFP